



# INCREASING POWER DENSITY FOR MOTOR DRIVES WITH SILICON CARBIDE

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1. Introduction to Apex Motor Drive Options
2. SiC vs GaN vs Silicon
3. Benefits of SiC in a Hybrid Architecture
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5. Commutation Schemes for Maximizing Motor Efficiency

# INTRODUCTION TO APEX MOTOR DRIVE OPTIONS

# WHO IS APEX MICROTECHNOLOGY?



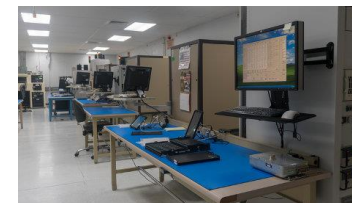
- Industry leader in high power analog devices since 1980
- Vertically integrated design and production facility located in Tucson, Arizona (USA)
- Subsidiary of HEICO, a successful and technology-driven aerospace, industrial, defense, and electronics company.
- ISO9001 & MIL-PRF-38534 Certified



Assembly



Thick Film



Test



Reflow

# WHAT DOES APEX DO IN MOTOR DRIVE?



## DC Brushed Motors (H-bridge)



**SA160**  
10A, 80V



**MSA260** IGBT  
20A, 450V



**SA50**  
5A, 80V

## DC Brushless Motors (3-phase)



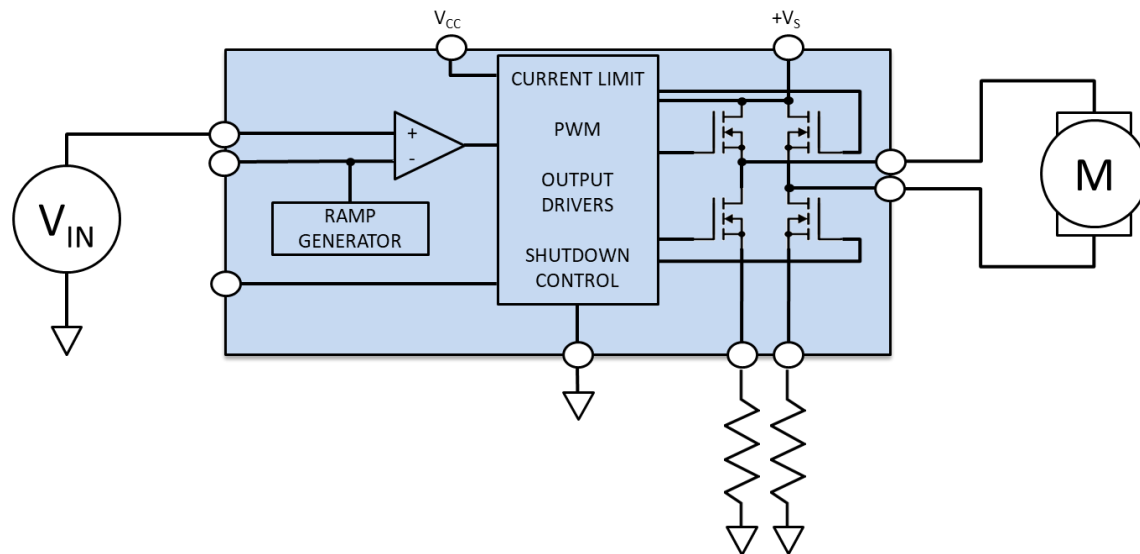
**SA306**  
8A, 60V



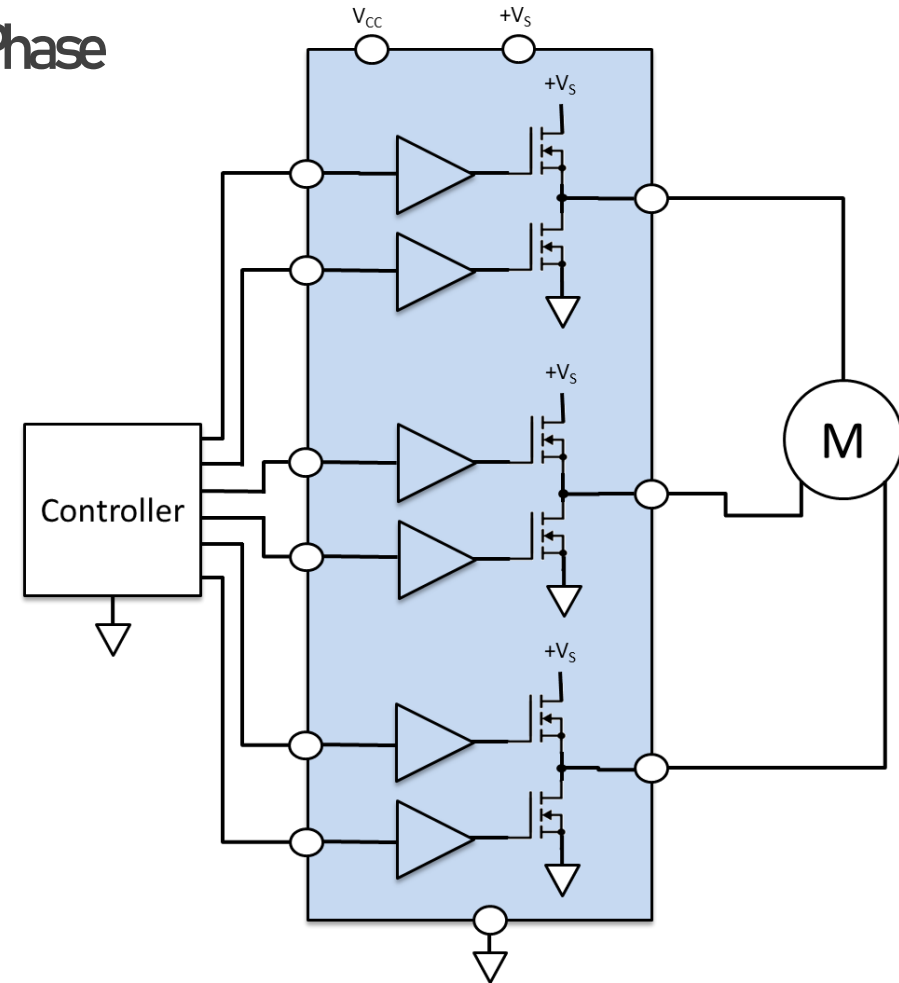
**SA310** NEW SiC  
30A, 650V

# APEX MOTOR DRIVE CIRCUITS - UNDER THE HOOD

## H-bridge



## 3-Phase

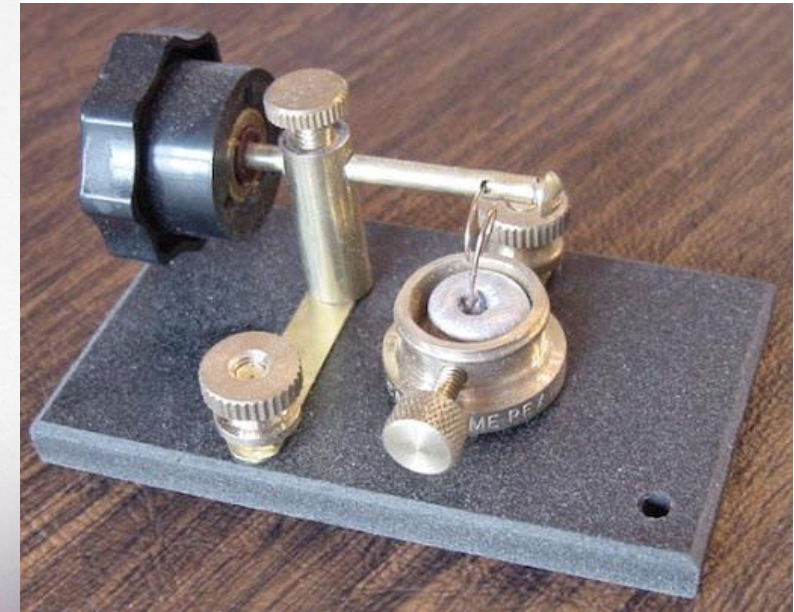
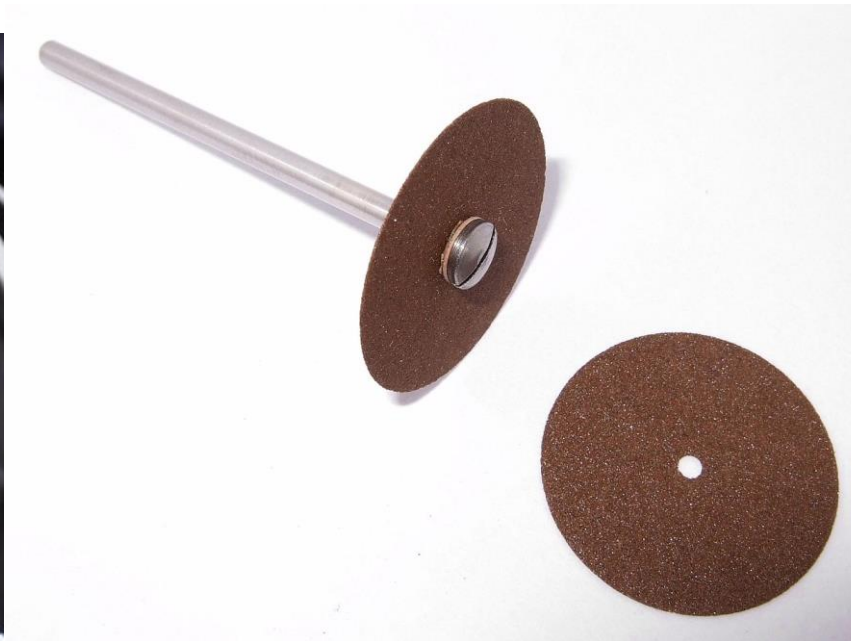


# SiC VS. GaN VS. Silicon

A comparison of switch technologies across applications

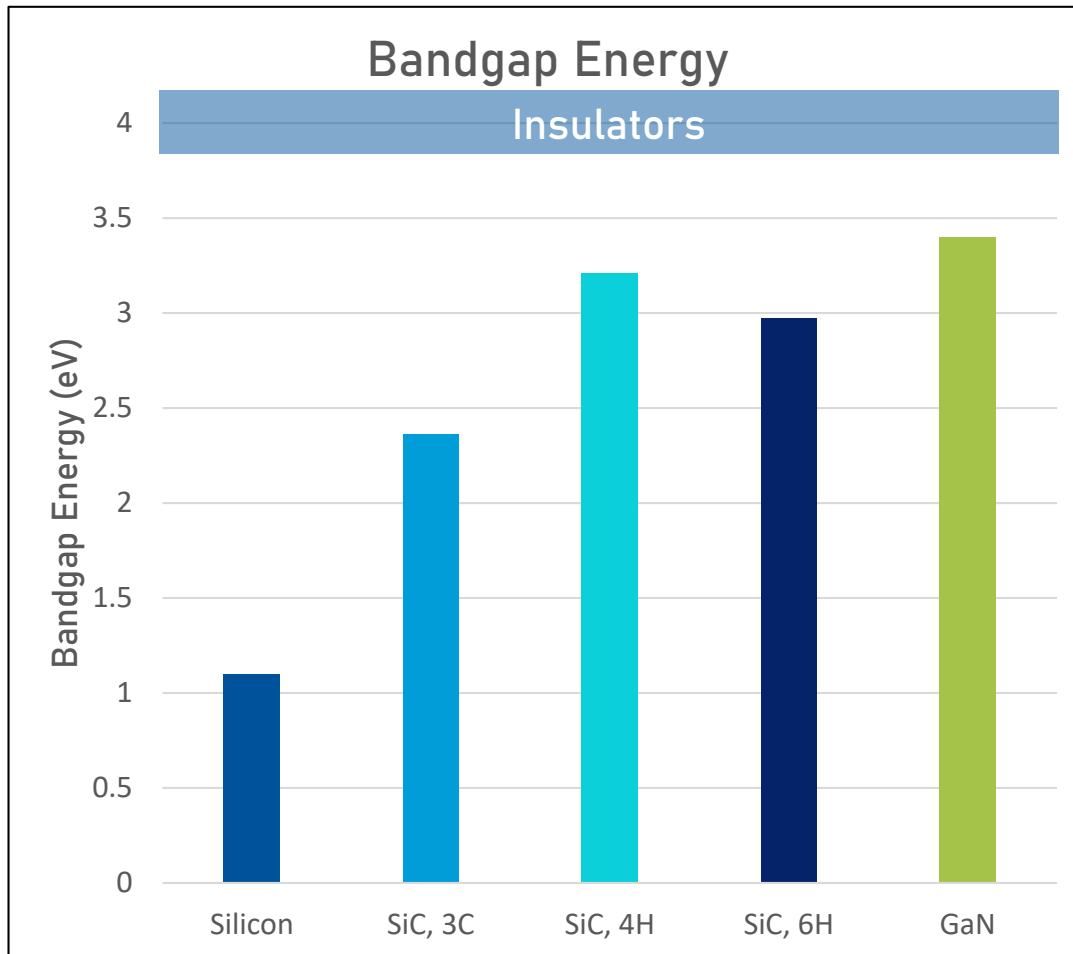
## WHAT IS SILICON CARBIDE?

- First used as a commercial semiconductor in 1906
  - Same year as Silicon
- Made by passing current through molten Silica/Carbon mixture
- Incredibly hard material, commonly used in abrasive tools, disc brakes



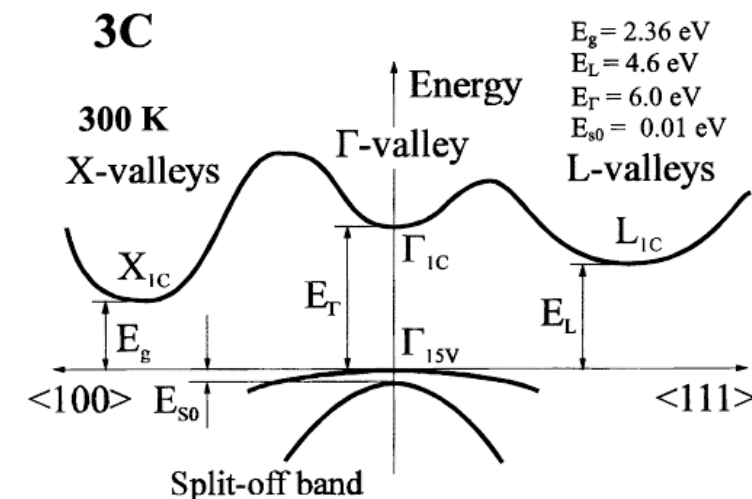


# BANDGAP ENERGY

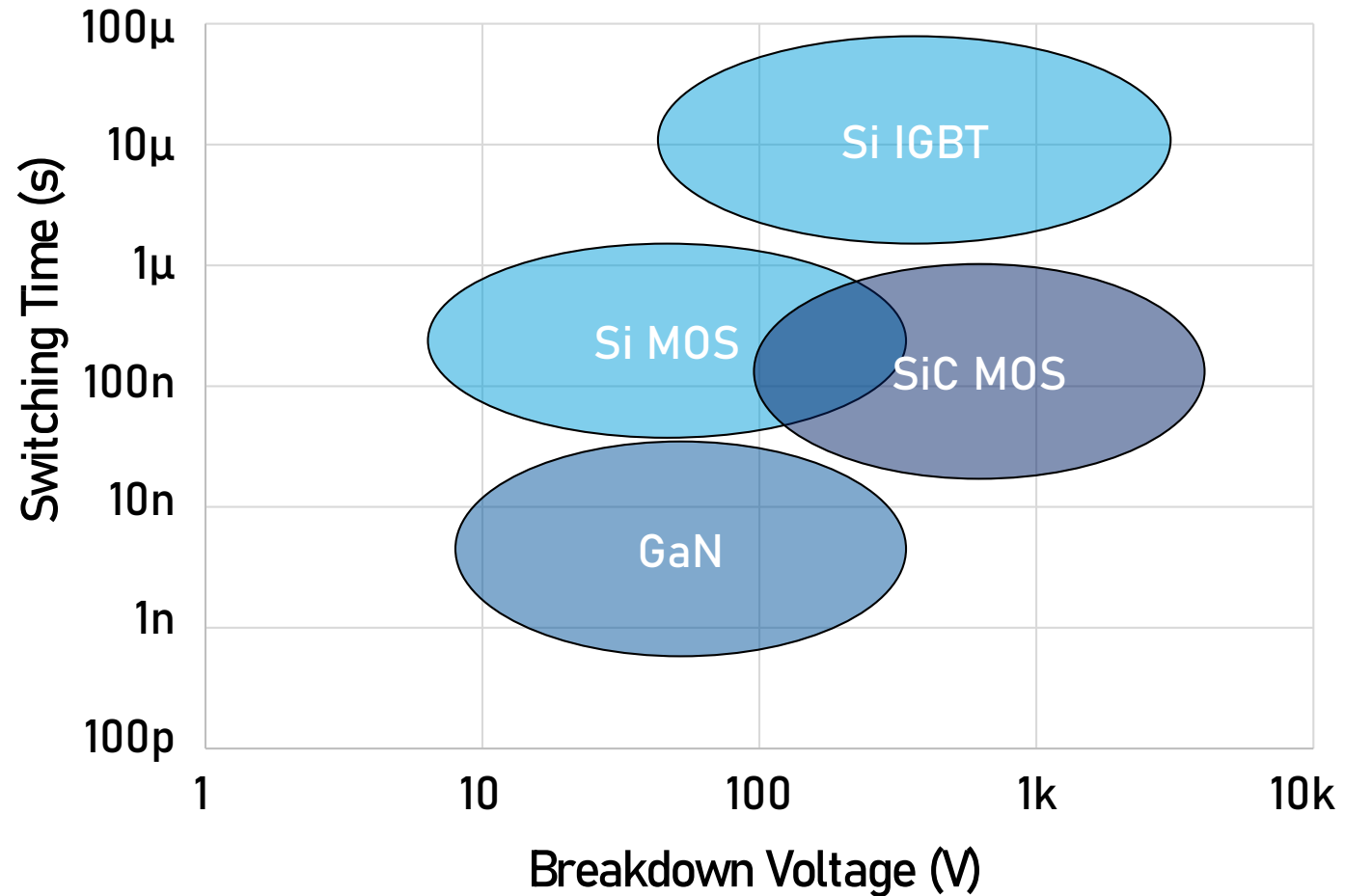


## SiC has up to 3 times higher bandgap energy than Silicon

- 10 times higher breakdown voltage
- Operation up to 1000°C



# TECHNOLOGY COMPARISON



# SILICON CARBIDE



Si 60V 120A 10m $\Omega$  83ns



SiC 600V 120A 10m $\Omega$  83ns

SiC offers higher voltage and temperature than equivalent Silicon FETs

- OR -

SiC offers HV FETs with LV specs (superior switching times and  $R_{DS(ON)}$ )



Si 650V 10A 1 $\Omega$  85ns



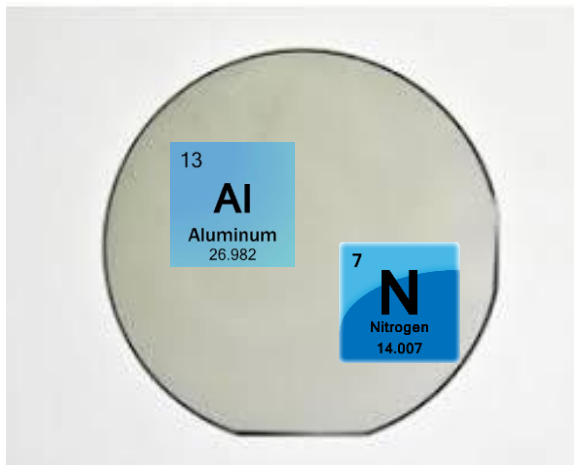
SiC 650V 100A 30m $\Omega$  40ns

# WHY IS IT SO EXPENSIVE?

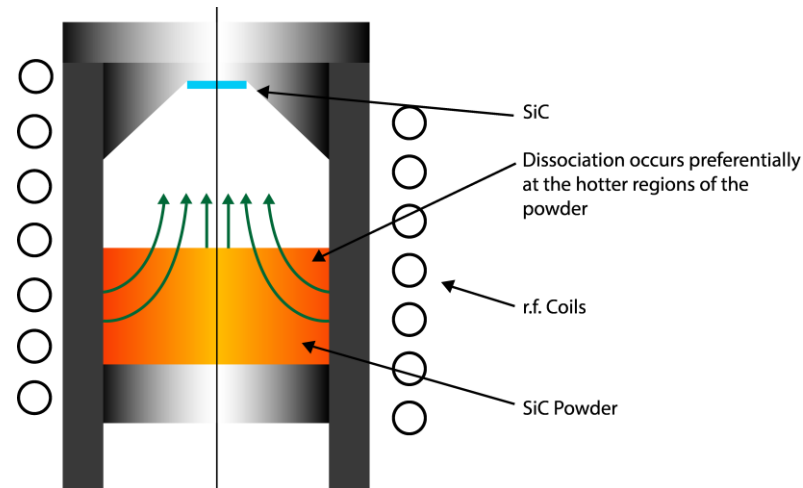
Most processing is identical to that of Silicon except:

- Crystal Growth - Physical Vapor Transport vs Float-Zone
- Wafering & polishing - very hard material
- Epitaxy - different dopants than Si

Epitaxy Materials



PVT Process



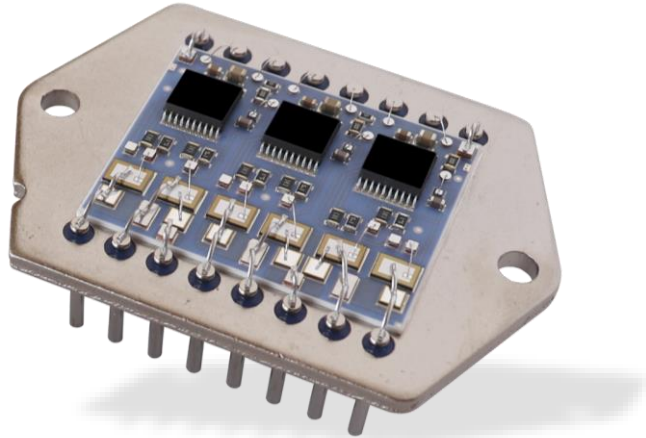
Polished Wafers



# BENEFITS OF SiC IN A HYBRID ARCHITECTURE

# WHAT IS A HYBRID CIRCUIT?

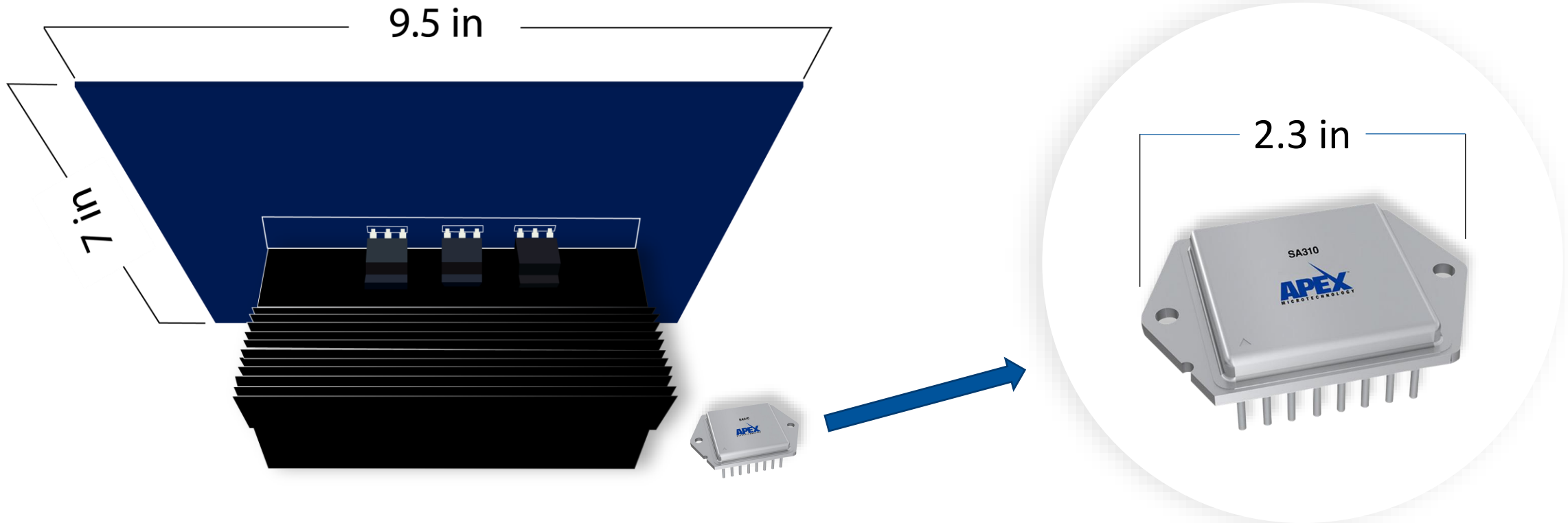
“electronic subassemblies [...] that can be fabricated as a separate module.” - Motorola



Hybrids typically include:

- Ceramic substrate
- Bare-Die components
- Wirebonds
- Thickfilm-printed conductors, resistors, and insulators

# ADVANTAGES OF HYBRID TECHNOLOGY

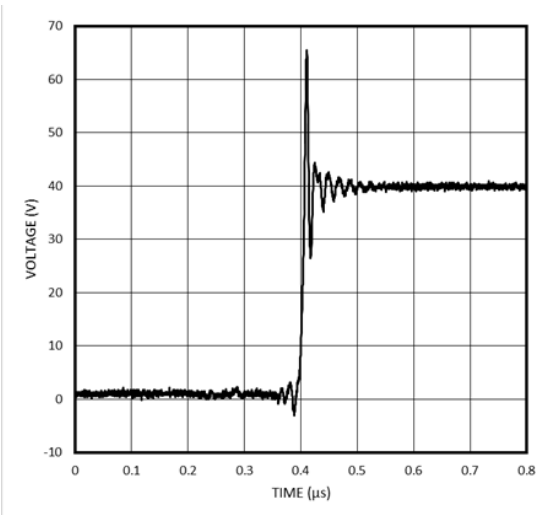
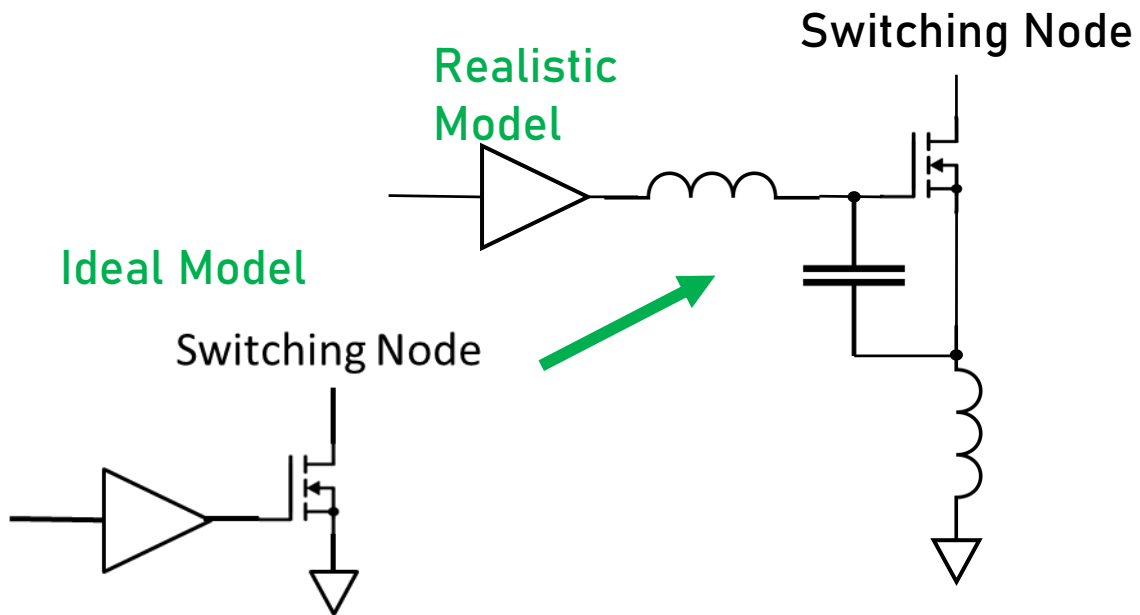


Bare Die allow for more dense circuit construction

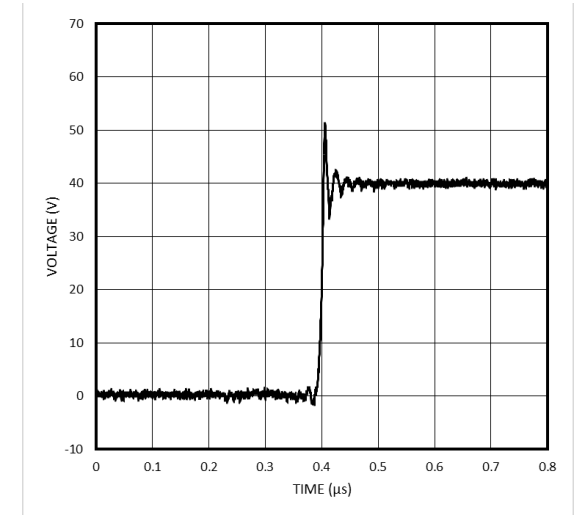
# ADVANTAGES OF HYBRID TECHNOLOGY

## Parasitics

Parasitic inductance in the gate-source loop is optimized over a discrete design.



Non-Integrated SiC Module



Apex Integrated SiC Module



# ADVANTAGES OF HYBRID TECHNOLOGY



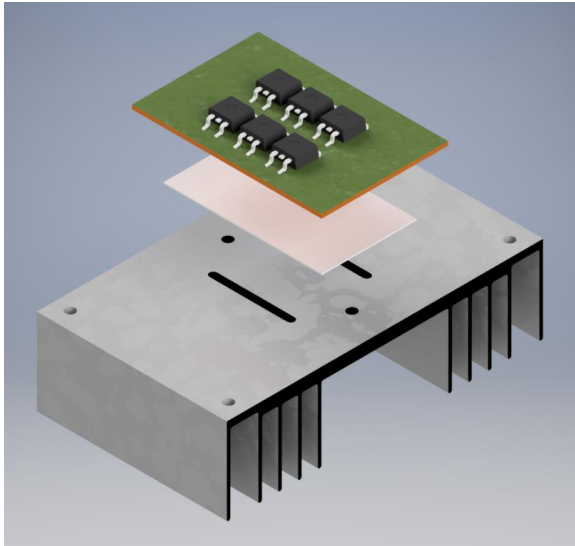
## Power Density

- Substrate choices make it easier to get the heat out
- Higher Thermal Conductivity leads to:
  - Lower temperature rise per Watt
  - More Watts per Cubic Centimeter

Material	Thermal Conductivity (W/m-K)
Copper	400
Beryllium Oxide	290
Aluminum	170
Aluminum Nitride	170
Aluminum Oxide	30
Silicon Nitride	30
FR-4 with Thermal Vias	16
FR-4	0.29

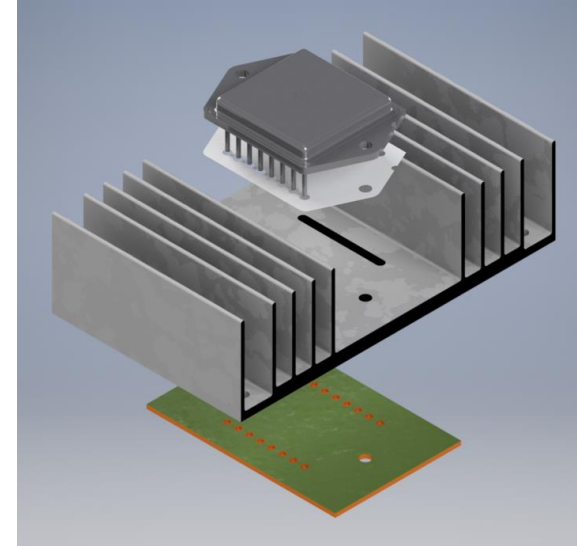
*Blue = Ceramic Material*

# DESIGN EXAMPLE – 650V SiC 30mΩ 3-PHASE MODULE



Discrete D<sup>2</sup>PAK Design

$$R_{\theta JA} = 3.81 \text{ }^{\circ}\text{C/W}$$
$$T_{\text{Junction}} = 175 \text{ }^{\circ}\text{C}$$
$$P_{\text{delivered}} = 8.2 \text{ kW}$$



Hybrid

$$R_{\theta JA} = 2.38 \text{ }^{\circ}\text{C/W}$$
$$T_{\text{Junction}} = 175 \text{ }^{\circ}\text{C}$$
$$P_{\text{delivered}} = 11.2 \text{ kW}$$

## 37% More Power Output!

# SILICON CARBIDE IN HYBRID ASSEMBLY- SUMMARY



- All else being equal, Hybrids offer the exact same advantages as Silicon Carbide
- Combining these technologies leads to compound benefits

	HYBRID	DISCRETE
Power Output	Higher	Lower
Power Density	Higher	Lower
Circuit Size	Smaller	Larger
Heatsink Size	Smaller	Larger
Switching Losses	Lower	Higher

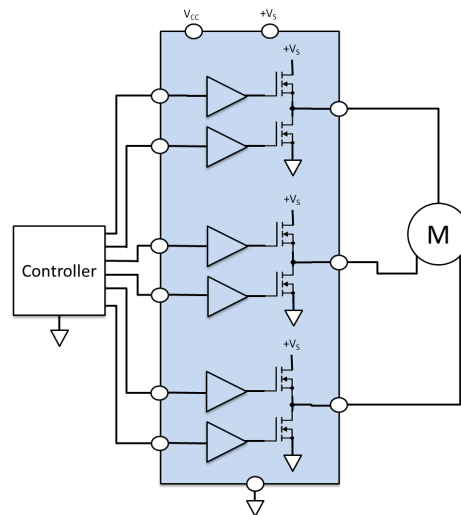
# HOW TO CONTROL APEX SiC PRODUCTS

Interfacing with an integrated Motor Drive module

# TYPES OF APEX MOTOR DRIVE MODULES

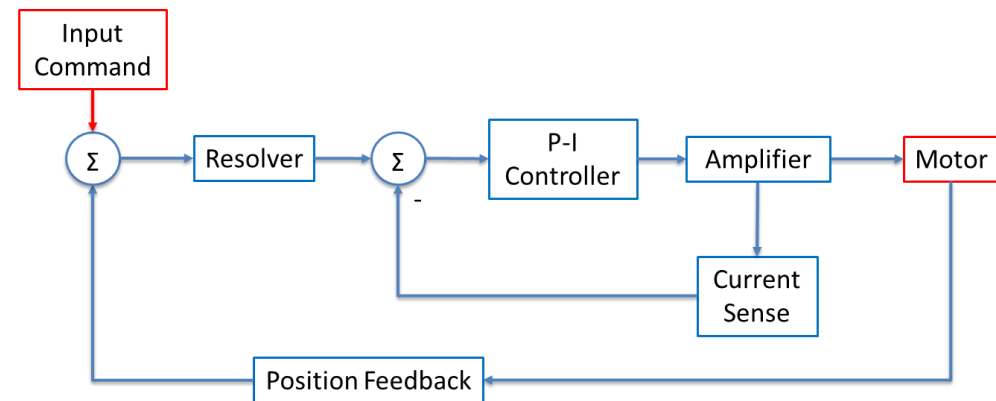
## Standard Modules

- User sends signals to turn each switch on/off.
- Closed-loop control created externally

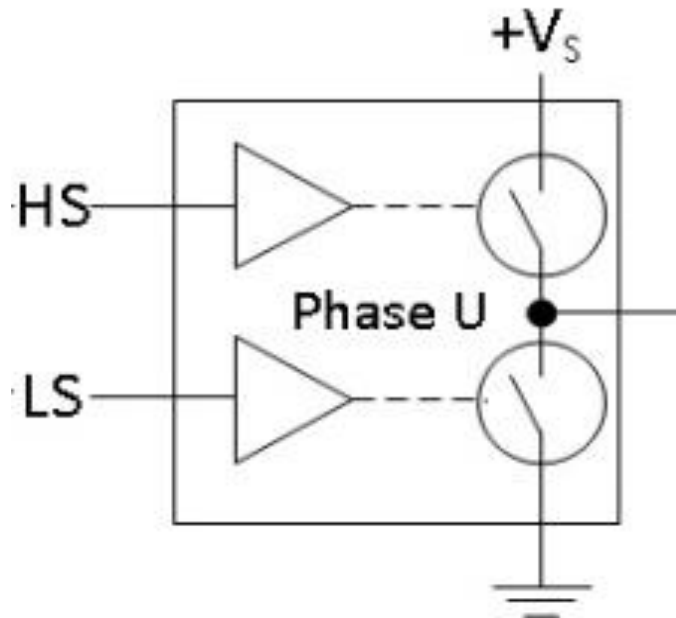


## Mixed Modules

- User sends commands to activate several functions
- Closed-loop control managed by the module



## Truth table for controlling the output state



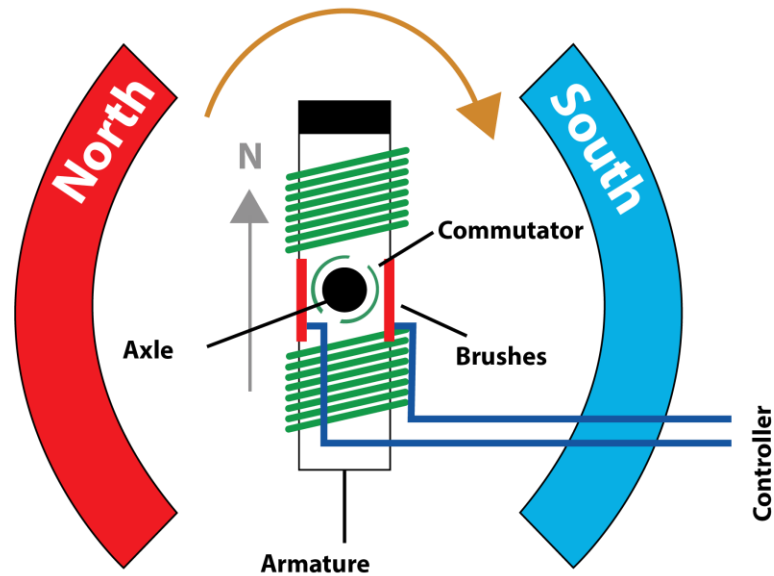
HS input	LS input	Output State
0	0	High-Impedance (HZ)
0	1	Ground (0)
1	0	High-Voltage (1)
1	1	Do not use

# COMMUTATION SCHEMES FOR MAXIMIZING MOTOR EFFICIENCY

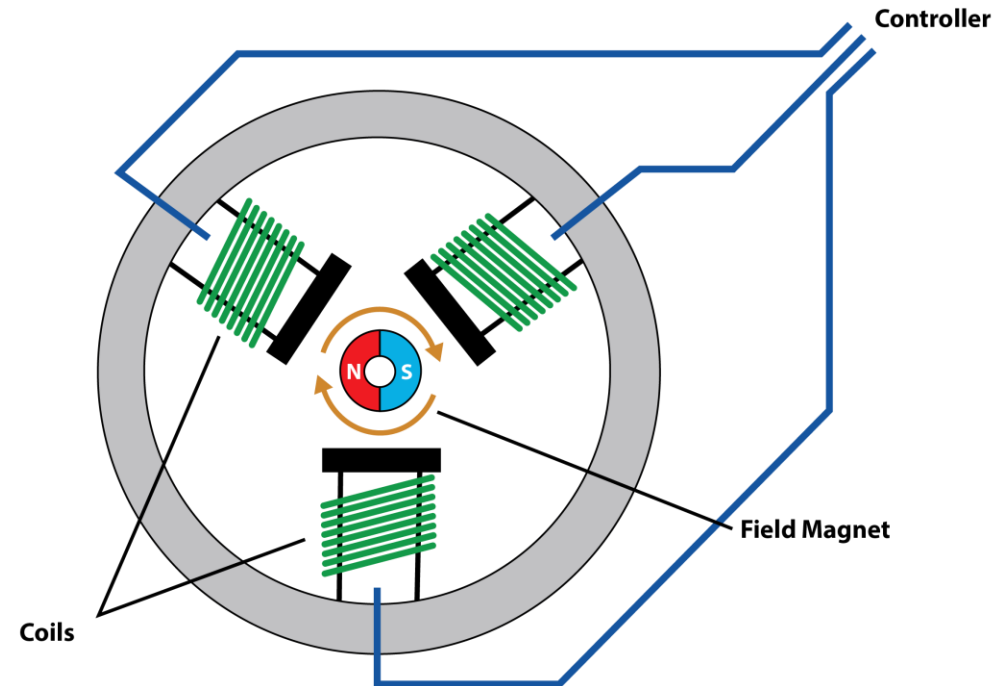
Sequencing the output states for various applications

# BRUSHED VS. BRUSHLESS

## Brushed DC Motor Mechanically Commutated

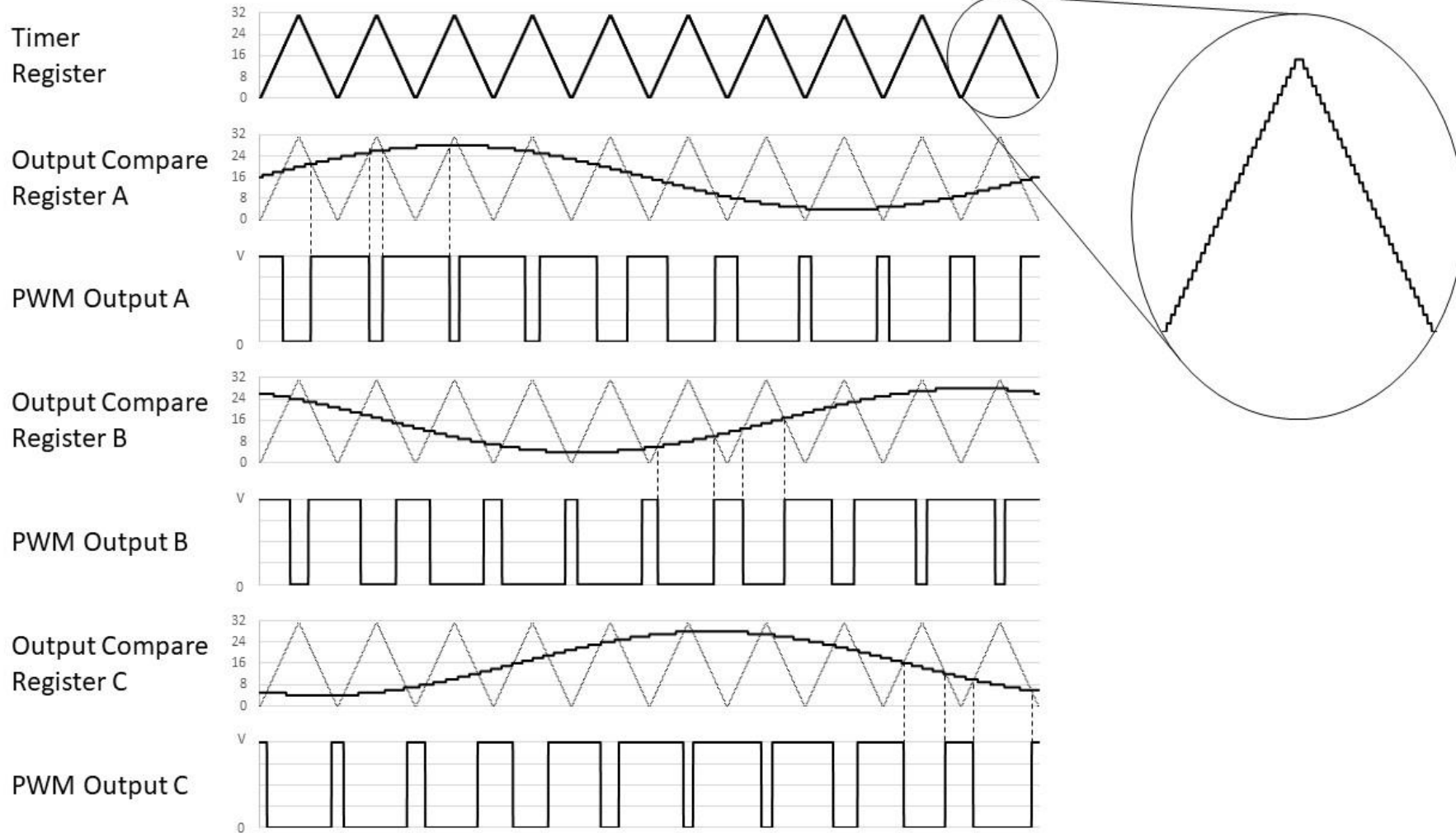


## Brushless DC Motor Electrically Commutated





# SINUSOIDAL COMMUTATION

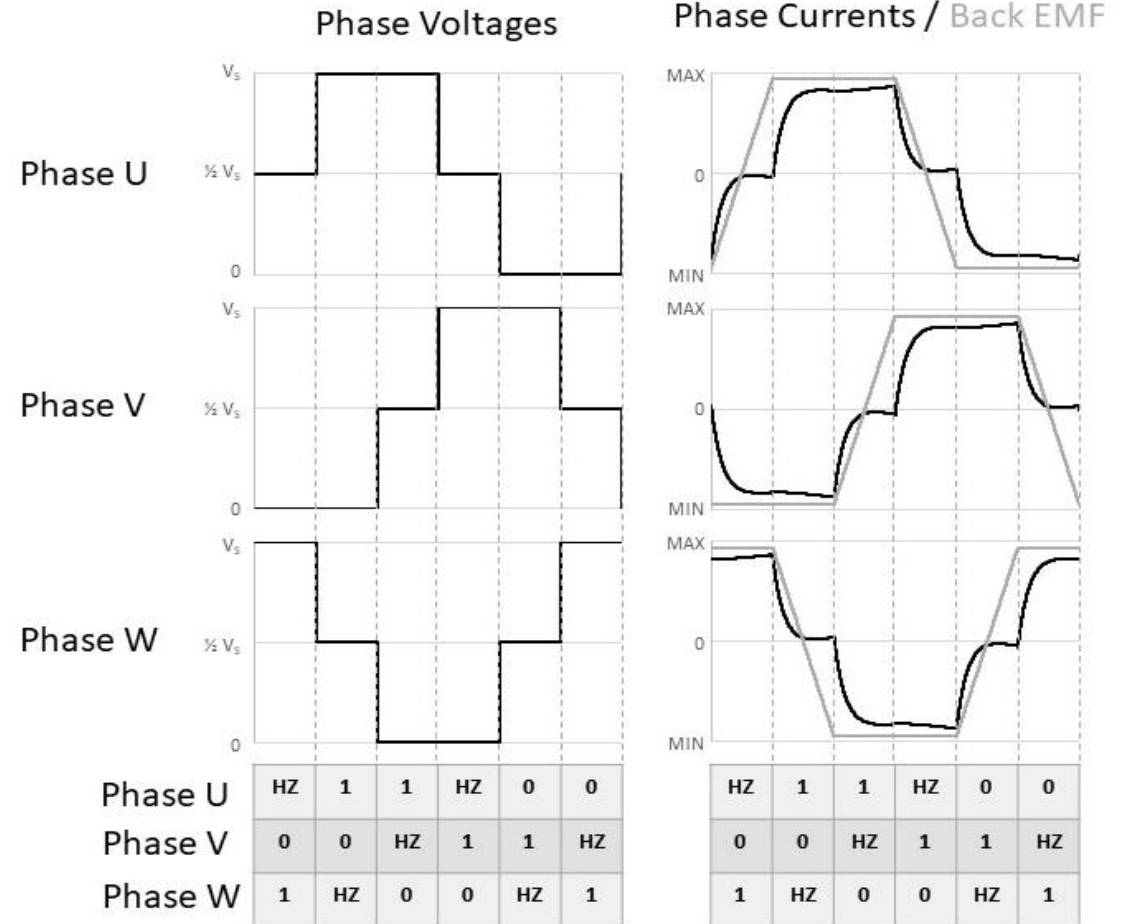


- Requires Most Complicated Controller Hardware.
- Recommended for PMSMs.
- Low Torque Ripple.
- Limited to Low RPMs.
- Requires Encoder

# TRAPEZOIDAL COMMUTATION



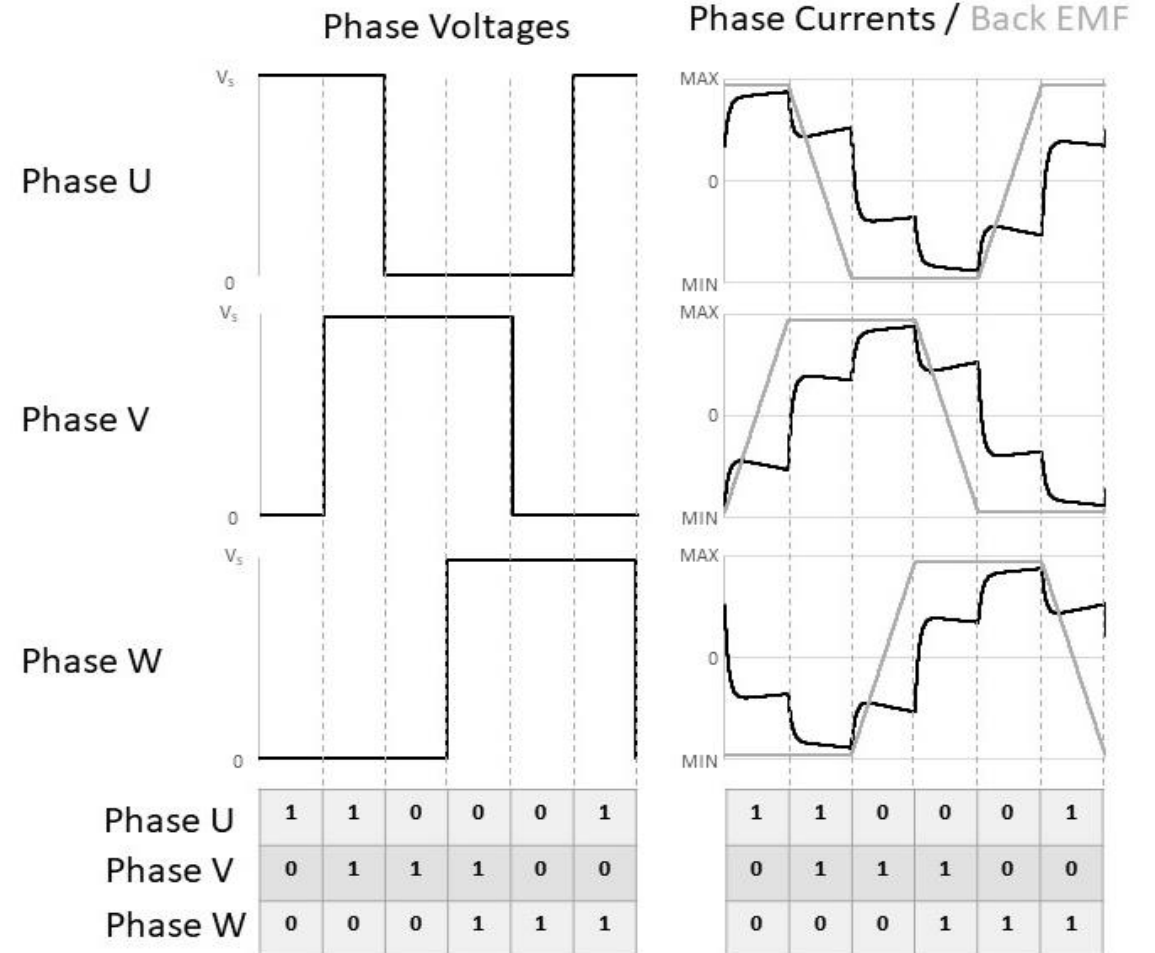
- Simplest Method – no dead-time required.
- Recommended for most BLDC motors.
- Low-speed torque is a challenge – use for high RPM applications
- Pairs well with Hall-effect sensors



# SIX-STEP COMMUTATION



- Simple, but does require dead-time
- Good option for BLDC motors
- Offers smoother torque than trapezoidal – energizes more phases.
- Pairs well with Hall-effect sensors





**APEX**

**MICROTECHNOLOGY**

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*P R E C I S I O N • P O W E R • A N A L O G*